

80um InGaAs APD Preamplifier Module

CR80AH-1550-200M

The CR80AH-1550-200M includes a 500um InGaAs Avalanche Photodiode with a hybrid preamplifier for the use in high speed, ultra-low light detection, in laser range finding, LIDAR and free space communication.

■ Features

- Built in 80um InGaAs APD+TIA
- High sensitivity: $\geq 100\text{kV/W}$
- High bandwidth: 200Mhz
- Wavelength range:900~1700nm
- Low noise and high reliability
- TO8 package with flat window

■ Applications

- LIDAR
- Laser range finding
- Free space optical communication (FSO)

■ Absolute Maximum Ratings

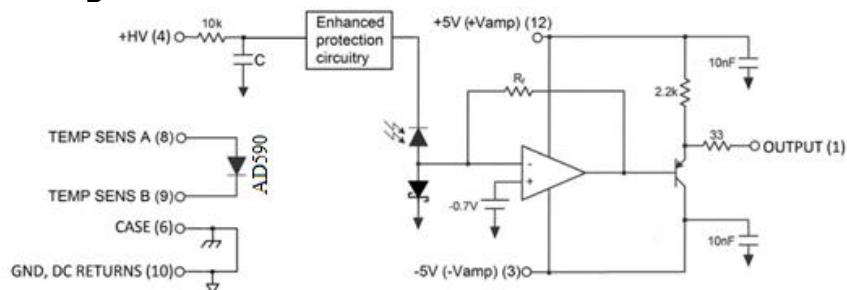
Parameter	Unit	Symbol	Rating
Reverse breakdown voltage	V	V_R	V_{BR}
Operating temperature	°C	T_C	-40 ~ +85
Storage temperature	°C	T_{STG}	-55 ~ +100
Maximum optical input power	mW	P_{in}	100
Module mains voltage	V	V_{cc}/V_{EE}	± 5
Power dissipation	mW	P_w	250
Soldering temperature(time)	°C	-	300 (10s)

Optical/Electrical Characteristics (T=25°C, unless otherwise stated)

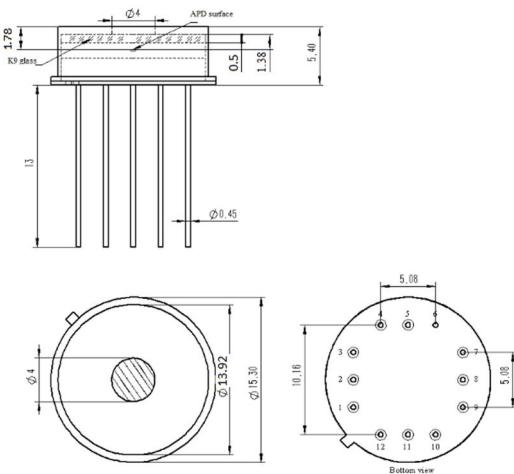
Parameter	Symbol	Value			Unit	Test conditions
		Min	Typ	Max		
Response Spectrum	λ	900~1700			nm	
Active Diameter	D		80		um	
Reverse breakdown voltage	V_{BR}	30		70	V	
Operating voltage	V_R	VR-3			V	M=10
Responsivity	R_V	100			kV/W	M=10, 1.55um@ $\tau=100\text{ns}$
Dynamic range	DY	25			dB	M=10, 1.55um @ $\tau=100\text{ns}$
-3dB bandwidth	BW		200		Mhz	M=10, 1.55um @ $\tau=100\text{ns}$
Rise/Fall time	t_r		1.75		ns	M=10, 1.55um @ $\tau=100\text{ns}$
Noise Equivalent Power	NEP		250		fW/ $\sqrt{\text{Hz}}$	

Output impedance	R_o		50		Ω	
Output Voltage Swing	V_o	0.7			V	
Positive Supply Current	I_{CC}			30	mA	
Negative Supply Current	I_{EE}			10	mA	50Ω Load
Temperature coefficient of V_{op} for constant gain	γ	0.06	0.10	0.15	$V/^\circ C$	-45~+85°C
Concentricity	ΔD			25	um	

Schematic Block Diagram



Block Diagram and Pin description



Pin description

PIN #	DESC	PIN #	DESC
1	OUTPUT	7	NC
2	NC	8	TEMP SENS A
3	-5V	9	TEMP SENS B
4	HV, APD BIAS	10	GND
5	NC	11	NC
6	CASE	12	+5V